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VDS (V) = 30V

ID = 5.8 A (VGS = 10V)

RDS(ON) 28m (VGS = 10V)

RDS(ON) 33m (VGS = 4.5V)

RDS(ON) 52m (VGS = 2.5V)

RDS(ON) 70m (VGS = 1.8V)

N-Channel MOSFET

1. Gate
2. Source
3. Drain

	Symbol	Rating	Unit
	VDS	30	
	VGS	w12	
TA=25		5.8	
TA=70		4.9	
	IDM	30	
TA=25		1.4	
TA=70		1	
t 10s		90	
Steady-State		125	
	RthJL		

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	V_{DSS}	I				